

General Description

The HG3085E +5V, half-duplex, ±15kV ESDprotected RS-485/RS-422-compatible transceivers feature one driver and one receiver. The HG3085E include a hot-swap capability to eliminate false transitions on the bus during power-up or live insertion.

TheHG3085E features reduced slew-rate drivers that minimize EMI and reduce reflections caused by improperly terminated cables, allowing error-free transmission up to 500kbps.

The HG3085E feature a 1/8-unit load receiver input impedance, allowing up to 256 transceivers on the bus. These devices are intended for half-duplex communications. All driver outputs are protected to ± 15 kV ESD using the Human Body Model.

TheHG3085 is available in an 8-pin SO package. The devices operate over the extended -40 % to +85 % temperature range.

ABSOLUTE MAXIMUM RATINGS

(All voltages referenced to GND.)

| Supply Voltage VCC+6V |
|--|
| DE, RE, DI0.3V to +6 |
| A, B8V to +13V |
| Short-Circuit Duration (RO, A, B) to GNDContinuous |
| Continuous Power Dissipation (TA = +70°C) |
| 8-Pin SO (derate 5.9mW/°C above +70°C)471mW |
| Operating Temperature Range40°C to +85°C |
| Junction Temperature+150°C |
| Storage Temperature Range65°C to +150°C |
| |

Features

- +5V Operation
- Hot-Swappable for Telecom Applications
- Enhanced Slew-Rate Limiting Facilitates
- Free Data Transmission
 Extended ESD Protection for RS-485 I/O Pins ±15kV Human Body Model
- 1/8Unit Load , Allowing Up to 256Transceivers on the Bus
- 8 Pin-SOP/DIP Package

Applications

- Isolated RS-485 Interfaces
- Utility Meters
- Industrial Controls
- Industrial Motor Drives
- Automated HVAC Systems

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Ordering Information

| PART | TEMP. RANGE | PIN-PACKAGE |
|------------|-------------|-------------|
| HG3085EEPA | -40°C∼+85°C | DIP8 |
| HG3085EESA | -40°C∼+85°C | SOP8 |



DC ELECTRICAL CHARACTERICS

(VCC = $+5V \pm 5\%$, TA = TMIN to TMAX, unless otherwise noted. Typical values are at VCC = +5V and TA = +25 °C.)

| PARAMETER | SYMBOL | CONDITIONS | MIN TYP MAX | UNITS |
|--|------------------|---|--------------------|-------|
| DRIVER | | | | |
| Differential Driver Output (no load) | V _{OD1} | Figure1 | 5 | V |
| | | Figure1,R = 50Ω (RS- 422) | 2.0 | |
| Differential Driver Output | Vod2 | Figure1,R = 27Ω (RS- 485) | 1.5 | V |
| Change in Magnitude of Differential Output Voltage (Note 2) | ΔV _{OD} | Figure1,R =50Ωor R= 27Ω | 0.2 | V |
| Driver Common-Mode Output Voltage | Voc | Figure1,R=50 Ω or R = 27 Ω | 3 | V |
| Change In Magnitude of Common-Mode Voltage (Note 2) | ∆Voc | Figure1,R=50 Ω or R = 27 Ω | 0.2 | V |
| Input High Voltage | VIH1 | DE, DI, RE, | 2.0 | V |
| Input Low Voltage | VIL1 | DE, DI, RE, | 0.8 | V |
| DI Input Hysteresis | VHYS | WS3085 | 100 | mV |
| Input Current | I _{IN1} | DE, DI, RE | ±2 | μA |
| Input Current (A and B) | I _{IN4} | DE = GND, V _{CC} =GND or 5.25V V _{IN} = -7V | 125 -75 | μΑ |
| Driver Short-Circuit Output Current (Note 3) | V _{OD1} | $-7V \le V_{OUT} \le V_{CC}$ | -250 | mV |
| RECEIVER | | | | |
| Receiver Differential Threshold Voltage | VTH | $\text{-7V} \leq V_{CM} \leq \text{+12V}$ | -200 -125 -50 | mV |
| Receiver Input Hysteresis | ΔV_{TH} | | 25 | mV |
| Receiver Output High Voltage | V _{OH} | $I_{O} = 4mA, V_{ID} = -200mV;$ | Vcc-1.5 | V |
| Receiver Output Low Voltage | Vol | $I_O = -4mA$, $V_{ID} = -50mV$ | 0.4 | V |
| Three-State Output Current at Receiver | I _{OZR} | $0.4V \leq V_O \leq 2.4V$ | ±1 | μΑ |
| Receiver Input Resistance | Rin | $\text{-7V} \leq V_{CM} \leq \text{+12V}$ | 96 | kΩ |
| Receiver Output Short-Circuit Current | IOSR | $0V \leq V_{RO} \leq V_{CC}$ | ±7 ±95 | mA |
| SUPPLY CURRENT | | | | |
| Supply Current | Icc | No load, DE = VCC RE = DI=GND or VCC DE = GND | 530 900 500 600 | μA |



SWITCHING CHARACTERISTICS

(VCC = $+5V \pm 5\%$, TA = TMIN to TMAX, unless otherwise noted. Typical values are at VCC = +5V and TA = +25 °C.)

| PARAMETER | SYMBOL | CONDITIONS | MIN TYP MAX | UNITS |
|---|----------------------------|---|------------------------------|-------|
| Driver Input to Output | tDPLH tDPHL | Figures3 and 5, RDIFF = 54 Ω , CL1 = CL2 = 100pF | 250 720 1000 250 720 1000 | ns |
| Driver Output Skew tDPLH - tDPHL | t DSKEW | Figures 3 and 5, RDIFF = 54Ω , CL1 = CL2 = $100pF$ | -3 ±100 | ns |
| Driver Rise or Fall Time | tDR, tDF | Figures 3 and 5, RDIFF = 54Ω , CL1 = CL2 = 100pF | 200 530 750 | ns |
| Maximum Data Rate | f _{MAX} | | 500 | kbps |
| Driver Enable to Output High | tDZH | Figures4 and 6, C _L = 100pF, S2 closed | 2500 | ns |
| Driver Enable to Output Low | tDZL | Figures4 and 6,C _L = 100pF, S1 closed | 2500 | ns |
| Driver Disable Time from Low | t _{DLZ} | Figures 4 and 6, C _L = 15pF, S1 closed | 100 | ns |
| Driver Disable Time from High | t _{DHZ} | Figures 4 and 6, C _L = 15pF, S2 closed | 100 | ns |
| Receiver Input to Output | tRPLH, tRPHL | Figures 7 and 9; $ V_{ID} \ge$ 2.0V;rise and fall time of $V_{ID} \le 15$ ns | 127 200 | ns |
| t _{RPLH} - t _{RPHL} Differential Receiver Skew | ^t RSKD | Figures 7 and 9; $ V_{ID} \ge$ 2.0V;rise and fall time of $V_{ID} \le 15$ ns | 3 ±30 | ns |
| Receiver Enable to Output Low | tRZL | Figures 2 and 8, C _L = 100pF, S1 closed | 20 50 | ns |
| Receiver Enable to Output High | trzh | Figures 2 and 8, C _L = 100pF, S2 closed | 20 50 | ns |
| Receiver Disable Time from Low | t _{RLZ} | Figures 2 and 8 , C _L = 100pF, S1 closed | 20 50 | ns |
| Receiver Disable Time from High | t _{RHZ} | Figures 2 and 8, C _L = 100pF, S2 closed | 20 50 | ns |
| Time to Shutdown | tSHDN | (Note 4) | 50 200 600 | ns |
| Driver Enable from Shutdown to Output High | tdzh(Shd N) | Figures 4 and 6, C _L = 15pF, S2 closed | 4500 | ns |
| Driver Enable from Shutdown to Output Low | ^t DZL(SHDN) | Figures 4 and 6, CL = 15pF, S1 closed | 4500 | ns |
| Receiver Enable from Shutdown to Output High | trzh(SHD N) | Figures 2 and 8, C _L = 100pF, S2 closed | 3500 | ns |
| Receiver Enable from Shutdown to Output Low | t _{RZL(SHDN}) | Figures 2 and 8, C _L = 100pF, S1 closed | 3500 | ns |

Note 4: The device is put into shutdown by bringing RE high and DE low. If the enable inputs are in this state for less than 50ns, the device is

guaranteed not to enter shutdown. If the enable inputs are in this state for at least 600ns, the device is guaranteed to have entered



HG3085E

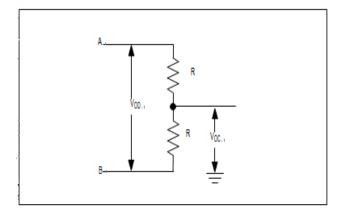


Figure 1. Driver DC Test Load

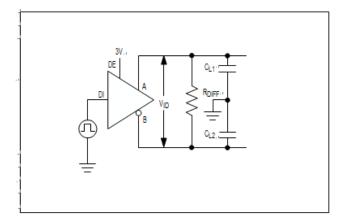


Figure 3 Driver Timing Test Circuit

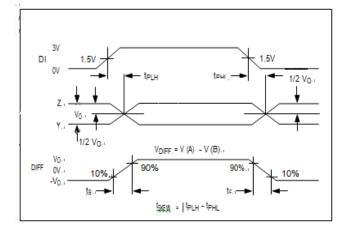


Figure 5 Driver Propagation Delays

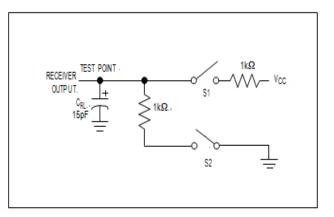


Figure 2. Receiver Enable/Disable Timing Test Load

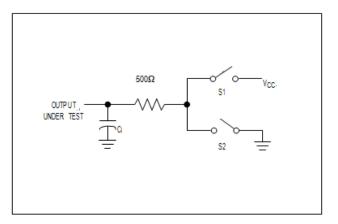


Figure 4 Driver Enable/Disable Timing Test Load

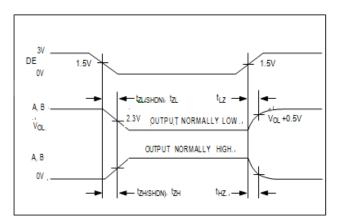
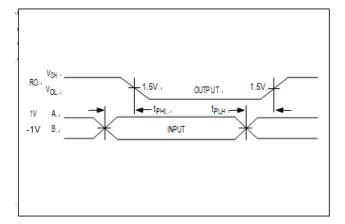


Figure 6. Driver Enable and Disable Times





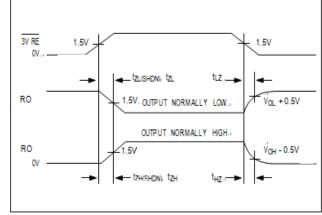


Figure 7. Receiver Propagation Delays



Pin Description

| PIN | NAME | FUNCTION |
|-----|------|---|
| 1 | RO | Receiver Output. When RE is low and if A - B \geq -50mV, RO will be high; if A - B \leq -200mV, RO will be low. |
| 2 | RE | Receiver Output Enable. Drive RE low to enable RO; RO is high impedance when RE is high. Drive RE high and DE low to enter low-power shutdown mode. RE is a hot-swap input (see the <i>Hot-Swap Capability</i> section for more details). |
| 3 | DE | Driver Output Enable. Drive DE high to enable driver outputs. These outputs are high impedance when DE is low. Drive RE high and DE low to enter low-power shutdown mode. DE is a hot-swap input (see the <i>Hot-Swap Capability</i> section for more details). |
| 4 | DI | Driver Input. With DE high, a low on DI forces non-inverting output low and inverting output high. Similarly, a high on DI forces non-inverting output high and inverting output low. |
| 5 | GND | Ground |
| 6 | А | Non-inverting Receiver Input and Non-inverting Driver Output |
| 7 | В | Inverting Receiver Input and Inverting Driver Output |
| 8 | Vcc | Positive Supply, V_{CC} = +5V ±5%. Bypass V_{CC} to GND with a 0.1µF capacitor. |



Function Table

| TRANSMITTING | | | | |
|--------------|---------|----|----------|--------|
| INPU | OUTPUTS | | | |
| RE | DE | DI | B/Z | A/Y |
| X | 1 | 1 | 0 | 1 |
| X | 1 | 0 | 1 | 0 |
| 0 | 0 | X | High-Z | High-Z |
| 1 | 0 | X | Shutdown | |

| RECEIVING | | | |
|-----------|--------|---------------|----------|
| INPUTS | | | OUTPUTS |
| RE | DE A-B | | RO |
| 0 | Х | \geq -0.05V | 1 |
| 0 | Х | \leq -0.2V | 0 |
| 0 | Х | Open/shorted | 1 |
| 1 | 1 | Х | High-Z |
| 1 | 0 | Х | Shutdown |

Applications Information

256 Transceivers on the Bus

The standard RS-485 receiver input impedance is $12k\Omega$ (one-unit load), and the standard driver can drive up to 32 unit loads. The HG3085 E family of transceivers have a 1/8-unit-load receiver input impedance (96k Ω), allowing up to 256 transceivers to be connected in parallel on one communication line. Any combination of these devices and/or other RS-485 transceivers with a total of 32 unit loads or less can be connected to the line.

Low-Power Shutdown Mode

Low-power shutdown mode is initiated by bringing both RE high and DE low. In shutdown, the devices typically draw only 2uA of supply current.

RE and DE may be driven simultaneously; the parts are guaranteed not to enter shutdown if RE is high and DE is low for less than 50ns. If the inputs are in this state for at least 600ns, the parts are guaranteed to enter shutdown.

Reduced EMI and Reflections

HG3085E is slew-rate limited, minimizing EMI and reducing reflections caused by improperly terminated cables.

Driver Output Protection

Two mechanisms prevent excessive output current and power dissipation caused by faults or by bus contention. The first, a fold-back current limit on the output stage, provides immediate protection against short circuits over the whole common-mode voltage range (see Typical Operating Characteristics). The second, a thermal shutdown circuit, forces the driver outputs into a high-impedance state if the die temperature becomes excessive.



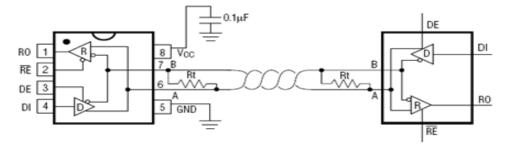


Figure 9 3085 Pin Configuration and Typical Half-Duplex Operating Circuit

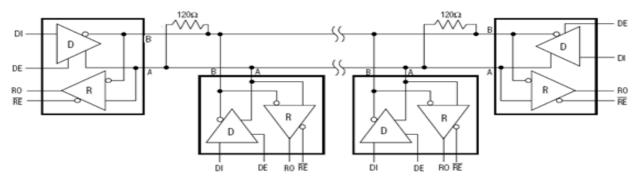


Figure 10 Typical Half-Duplex RS-485 Network